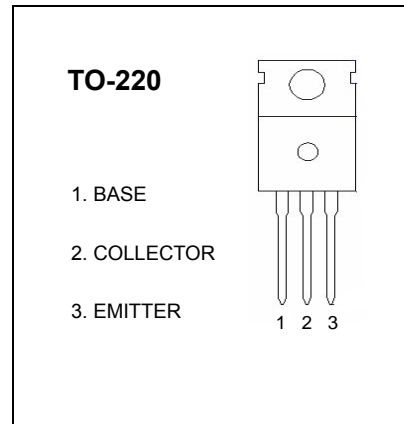


## TO-220 Plastic-Encapsulate Transistors

### TIP31/31A/31B/31C TRANSISTOR (NPN)

#### FEATURES

Medium Power Linear Switching Applications



#### MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	TIP31	TIP31A	TIP31B	TIP31C	Unit
V <sub>CBO</sub>	Collector-Base Voltage	40	60	80	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	40	60	80	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5				V
I <sub>C</sub>	Collector Current	3				A
P <sub>C</sub>	Collector Power Dissipation	2				W
R <sub>θJA</sub>	Thermal Resistance from Junction to Ambient	62.5				
T <sub>J</sub>	Junction Temperature	150				°C
T <sub>stg</sub>	Storage Temperature	-55~+150				°C

#### ELECTRICAL CHARACTERISTICS (Ta=25°C unless other wise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	TIP31 TIP31A TIP31B TIP31C V <sub>(BR)CBO</sub>	I <sub>C</sub> = 1mA, I <sub>E</sub> =0	40 60 80 100		V
Collector-emitter breakdown voltage *	TIP31 TIP31A TIP31B TIP31C V <sub>CEO(sus)</sub>	I <sub>C</sub> = 30mA, I <sub>B</sub> =0	40 60 80 100		V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 1mA, I <sub>C</sub> =0	5		V
Collector cut-off current	TIP31 TIP31A TIP31B TIP31C I <sub>CBO</sub>	V <sub>CB</sub> =40V, I <sub>E</sub> =0 V <sub>CB</sub> =60V, I <sub>E</sub> =0 V <sub>CB</sub> =80V, I <sub>E</sub> =0 V <sub>CB</sub> =100V, I <sub>E</sub> =0		200	μA
Collector cut-off current	TIP31/31A TIP31B/31C I <sub>CEO</sub>	V <sub>CE</sub> = 30V, I <sub>B</sub> = 0 V <sub>CE</sub> = 60V, I <sub>B</sub> = 0		0.3	mA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0		1	mA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> = 4V, I <sub>C</sub> = 1A	25		
	h <sub>FE(2)</sub>	V <sub>CE</sub> =4 V, I <sub>C</sub> = 3A	15	75	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =3A, I <sub>B</sub> =0.375A		1.2	V
Base-emitter voltage	V <sub>BE(on)</sub>	V <sub>CE</sub> = 4V, I <sub>C</sub> =3A		1.8	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =0.5A	3		MHZ

\* Pulse Test: PW≤300μs, Duty Cycle≤2%.